## NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE40H21A uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

•  $V_{DS} = 40V, I_{D} = 210A$ 

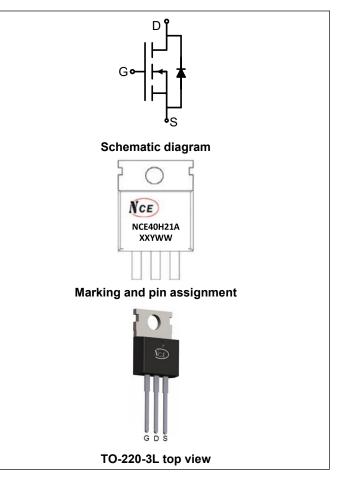
 $R_{DS(ON)} < 2.4 m\Omega$  @  $V_{GS}=10V$ 

- Excellent logic level drive capability
- High density cell design for ultra low RDS(ON)
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation

### **Application**

- Power switching applications
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED! 100% ΔVds TESTED!



**Package Marking and Ordering Information** 

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE40H21A	NCE40H21A	TO-220-3L	-	-	-

### Absolute Maximum Ratings (T<sub>C</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	210	А
Drain Current-Continuous(100℃)	I <sub>D</sub> (100°C)	148	А
Pulsed Drain Current (T <sub>c</sub> =25℃)	I <sub>DM</sub>	840	А
Maximum Power Dissipation	P <sub>D</sub>	200	W
Derating factor		1.34	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1936	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case	Rejc	0.75	°C/W



# Electrical Characteristics (TC=25°Cunless otherwise noted)

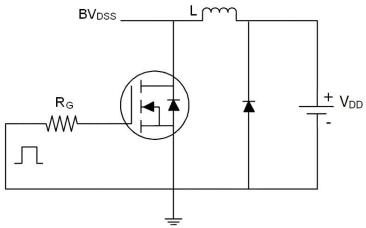
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	40	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	2	2.4	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =15V,I <sub>D</sub> =30A	-	60	-	S
Dynamic Characteristics (Note4)		,	'		1	
Input Capacitance	Clss	N 00N/N 0N/	-	9800	-	PF
Output Capacitance	Coss	$V_{DS}$ =20V, $V_{GS}$ =0V, F=1.0MHz	-	1049	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UMHZ	-	813	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	19	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =20V,R <sub>L</sub> =1 $\Omega$ ,	-	70	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =2.5 $\Omega$	-	78	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	53	-	nS
Total Gate Charge	Qg	V -20VI -20A	-	191	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=20V,I_{D}=20A,$	-	40.7	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	58	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	210	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, I <sub>F</sub> = 20A	-	30	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	24	-	nC
Forward Turn-On Time	ton	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				
	•		-			-

#### Notes:

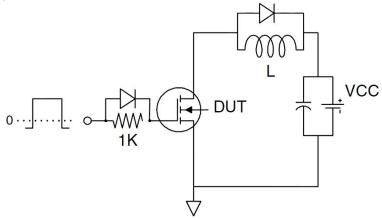
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V<sub>DD</sub>=20V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

# **Test Circuit**

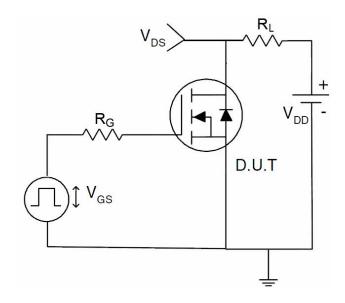
# 1) E<sub>AS</sub> Test Circuits



# 2) Gate Charge Test Circuit

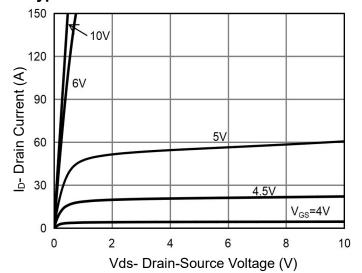


# 3) Switch Time Test Circuit

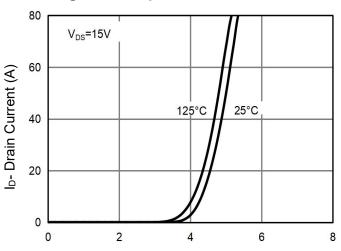




## **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



Vgs- Gate-Source Voltage (V)

**Figure 2 Transfer Characteristics** 

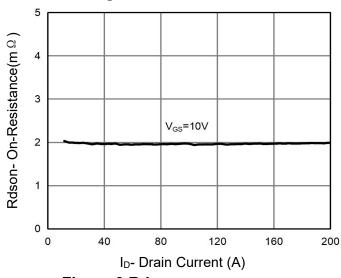


Figure 3 Rdson- Drain Current

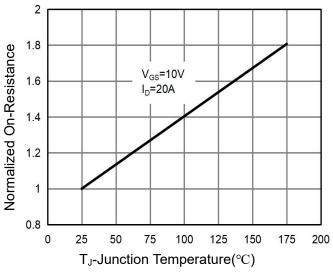
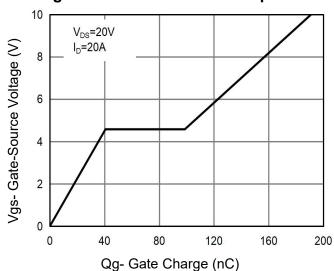


Figure 4 Rdson-JunctionTemperature





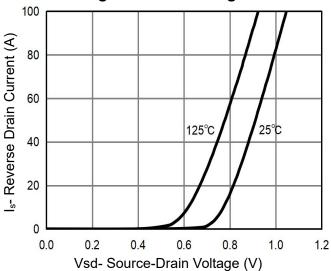


Figure 6 Source- Drain Diode Forward



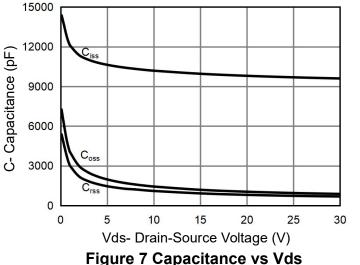


Figure 7 Capacitance vs Vds

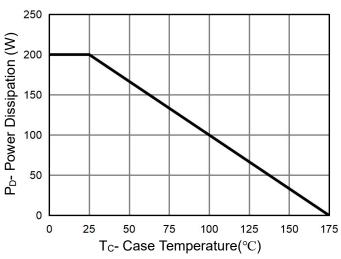


Figure 9 Power De-rating

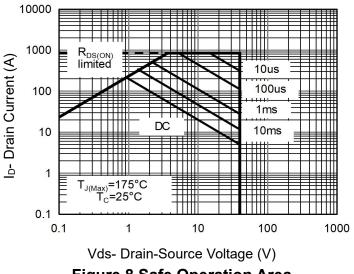


Figure 8 Safe Operation Area

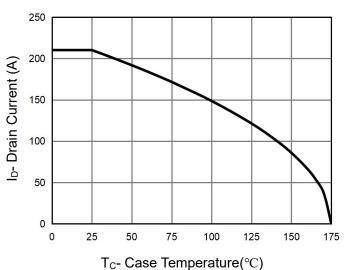


Figure 10 ID Current De-rating



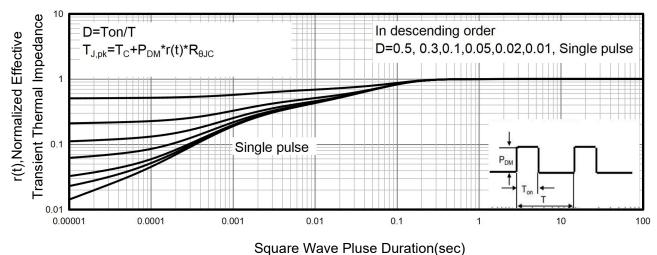
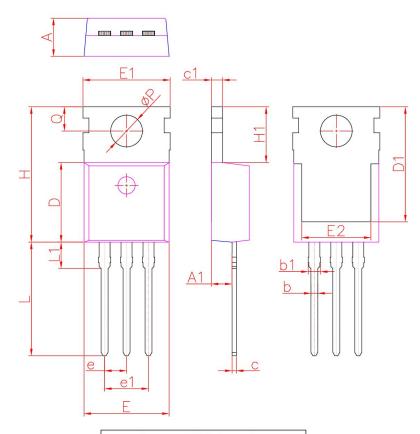


Figure 11 Normalized Maximum Transient Thermal Impedance

# **TO-220-3L Package Information**



TO220				
DIM.	MIN.	NOM.	MAX.	
Α	4.20	4.40	4.60	
A1	2.25	2.40	2.55	
b	0.70	0.80	0.90	
b1	1.17	1.27	1.37	
С	0.33	0.50	0.65	
c1	1.20	1.30	1.40	
D	8.95	9.20	9.75	
D1	13.10	13.30	13.50	
Е	9.74	9.84	10.04	
E1	9.91	10.08	10.25	
E2	7.90	8.00	8.10	
е	2.54BSC			
e1	5.08BSC			
Н	15.45	15.65	15.85	
H1	6.30	6.45	6.60	
L	12.90	13.13	13.40	
L1	2.85	3.05	3.25	
Q	2.65	2.80	2.95	
ØΡ	3.40	3.68	3.80	
All dimensions in millimeters				

### http://www.ncepower.com

# NCE40H21A

## **Revision History**

Revision	Date	Subjects
V1.0	2025.08	Product data sheet

#### **Attention**

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